## NSN 5961-01-579-6615

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lol code assembly, wire, dio, anti surface warfare improvement program (aip)

## Voltage Rating In Volts Per Characteristic:

400.0 repetitive peak reverse voltage

**Product Name:** 

Fast switching fast rectifier

## **Special Features:**

Fast switching for high effeciency; low forward voltage drop; low leakage current; high forward current operation; high forward surge capability; solder dip 260 degrees c; component in accordance to rohs 2002/95/ec and weee 2002/96/ec; maximum repetitive peak reverse voltage is 400; maximum rms voltage is 280; maximum dc blocking voltage is 400

Shelf Life:	She	lf	Life:
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N/a

**Unit Of Measure:** 

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**Demilitarization:** 

No

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